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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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 Remember to give due consideration to safety when making your circuit designs, with appropriate
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HSM88AS

Silicon Schottky Barrier Diode for Balanced Mixer



ADE-208-046E (Z)

Rev. 5 Jul. 1998

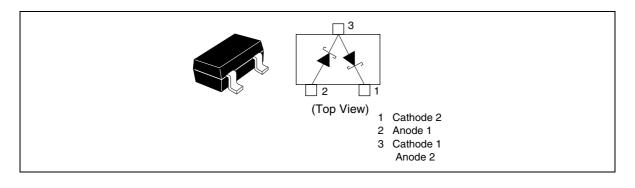
Features

- Proof against high voltage.
- MPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code
HSM88AS	C1	MPAK

Pin Arrangement



HSM88AS

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit		
Reverse voltage	V _R	10	V		
Average rectified current	l _o ^{*1}	15	mA		
Junction temperature	Tj	125	°C		
Storage temperature	Tstg	-55 to +125	°C		

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V _{F1}	350	_	420	mV	I _F = 1 mA
	V _{F2}	500	_	580	_	I _F = 10 mA
Reverse current	I _{R1}	_	_	0.2	μΑ	$V_R = 2V$
	I _{R2}	_	_	10	_	V _R = 10V
Capacitance	С	_	_	0.85	pF	$V_R = 0V$, $f = 1 MHz$
Capacitance deviation	ΔC	_	_	0.10	pF	$V_R = 0V$, $f = 1 MHz$
Forward voltage deviation	$\Delta V_{_{\rm F}}$	_	_	10	mV	I _F = 10 mA
ESD-Capability ^{*1}	_	30	_	_	V	C=200pF , Both forward and reverse direction 1 pulse.

Notes 1. Failure criterion; $I_R \ge 400$ nA at $V_R = 2$ V

Main Characteristic

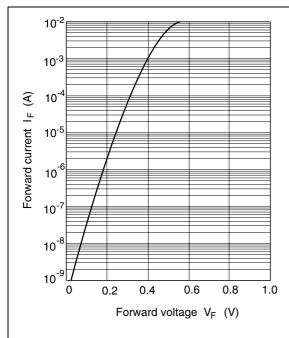
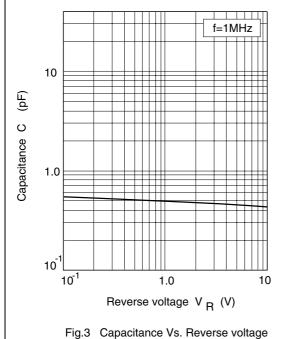


Fig.1 Forward current Vs. Forward voltage



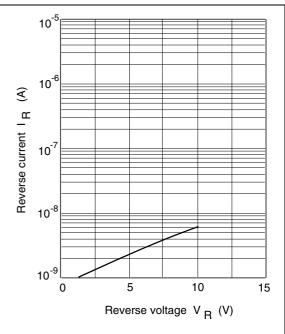
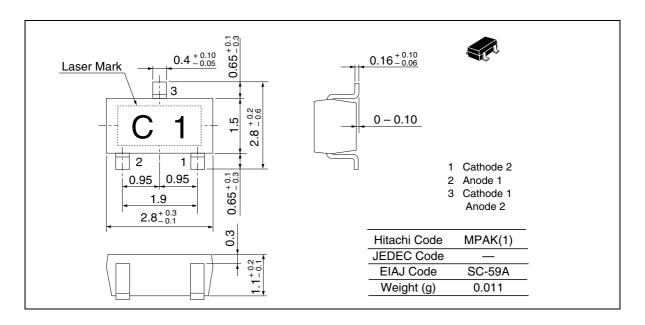


Fig.2 Reverse current Vs. Reverse voltage

HSM88AS

Package Dimensions

Unit: mm



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